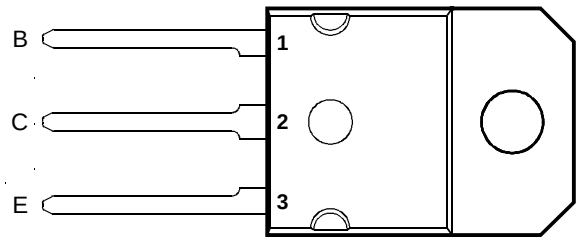
 JULY 1968 - REVISED MARCH 1997

- **Designed for Complementary Use with the TIP33 Series**
- **80 W at 25°C Case Temperature**
- **10 A Continuous Collector Current**
- **15 A Peak Collector Current**
- **Customer-Specified Selections Available**

SOT-93 PACKAGE
(TOP VIEW)



Pin 2 is in electrical contact with the mounting base.

MDTRAA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage (I_E = 0)	TIP34	V_{CBO}	-80	V
	TIP34A		-100	
	TIP34B		-120	
	TIP34C		-140	
Collector-emitter voltage (I_B = 0)	TIP34	V_{CEO}	-40	V
	TIP34A		-60	
	TIP34B		-80	
	TIP34C		-100	
Emitter-base voltage		V_{EBO}	-5	V
Continuous collector current		I_C	-10	A
Peak collector current (see Note 1)		I_{CM}	-15	A
Continuous base current		I_B	-3	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)		P_{tot}	80	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)		P_{tot}	3.5	W
Unclamped inductive load energy (see Note 4)		$½LI_C^2$	62.5	mJ
Operating junction temperature range		T_j	-65 to +150	°C
Storage temperature range		T_{stg}	-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds		T_L	250	°C

NOTES: 1. This value applies for $t_p \leq 0.3$ ms, duty cycle ≤ 10%.
2. Derate linearly to 150°C case temperature at the rate of 0.64 W/°C.
3. Derate linearly to 150°C free air temperature at the rate of 28 mW/°C.
4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH, $I_{B(on)}$ = -0.4 A, R_{BE} = 100 Ω, $V_{BE(off)}$ = 0, R_S = 0.1 Ω, V_{CC} = -20 V.

JULY 1968 - REVISED MARCH 1997

electrical characteristics at 25°C case temperature

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$	Collector-emitter breakdown voltage	I_C = -30 mA (see Note 5)	I_B = 0	TIP34 TIP34A TIP34B TIP34C	-40 -60 -80 -100			V
I_{CES}	Collector-emitter cut-off current	V_{CE} = -80 V V_{CE} = -100 V V_{CE} = -120 V V_{CE} = -140 V	V_{BE} = 0 V_{BE} = 0 V_{BE} = 0 V_{BE} = 0	TIP34 TIP34A TIP34B TIP34C			-0.4 -0.4 -0.4 -0.4	mA
I_{CEO}	Collector cut-off current	V_{CE} = -30 V V_{CE} = -60 V	I_B = 0 I_B = 0	TIP34/34A TIP34B/34C			-0.7 -0.7	mA
I_{EBO}	Emitter cut-off current	V_{EB} = -5 V	I_C = 0				-1	mA
h_{FE}	Forward current transfer ratio	V_{CE} = -4 V V_{CE} = -4 V	I_C = -1 A I_C = -3 A	(see Notes 5 and 6)	40 20		 100	
$V_{CE(sat)}$	Collector-emitter saturation voltage	I_B = -0.3 A I_B = -2.5 A	I_C = -3 A I_C = -10 A	(see Notes 5 and 6)			-1 -4	V
V_{BE}	Base-emitter voltage	V_{CE} = -4 V V_{CE} = -4 V	I_C = -3 A I_C = -10 A	(see Notes 5 and 6)			-1.6 -3	V
h_{fe}	Small signal forward current transfer ratio	V_{CE} = -10 V	I_C = -0.5 A	f = 1 kHz	20			
$\|h_{fe}\|$	Small signal forward current transfer ratio	V_{CE} = -10 V	I_C = -0.5 A	f = 1 MHz	3			

NOTES: 5. These parameters must be measured using pulse techniques, t_p = 300 µs, duty cycle ≤ 2%.
6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			1.56	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			35.7	°C/W

resistive-load-switching characteristics at 25°C case temperature

PARAMETER		TEST CONDITIONS †			MIN	TYP	MAX	UNIT
t_{on}	Turn-on time	I_C = -6 A	$I_{B(on)}$ = -0.6 A	$I_{B(off)}$ = 0.6 A		0.4		µs
t_{off}	Turn-off time	$V_{BE(off)}$ = 4 V	R_L = 5 Ω	t_p = 20 µs, dc ≤ 2%		0.7		µs

† Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

TYPICAL CHARACTERISTICS

TYPICAL DC CURRENT GAIN vs COLLECTOR CURRENT

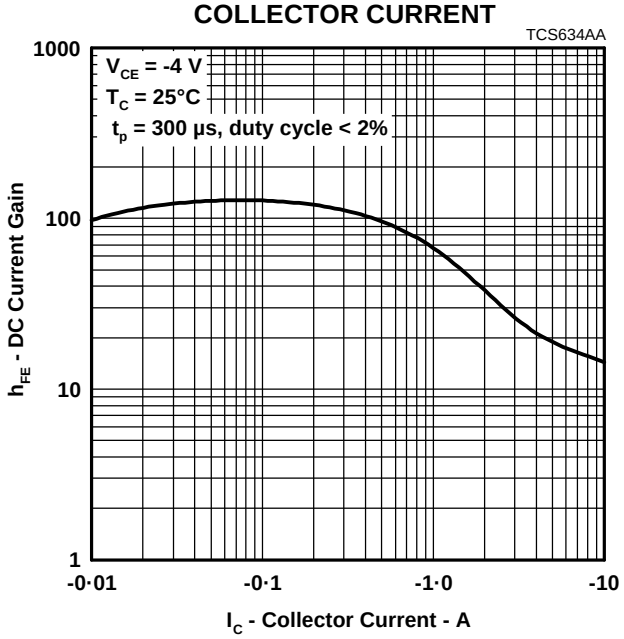


Figure 1.

COLLECTOR-EMITTER SATURATION VOLTAGE vs BASE CURRENT

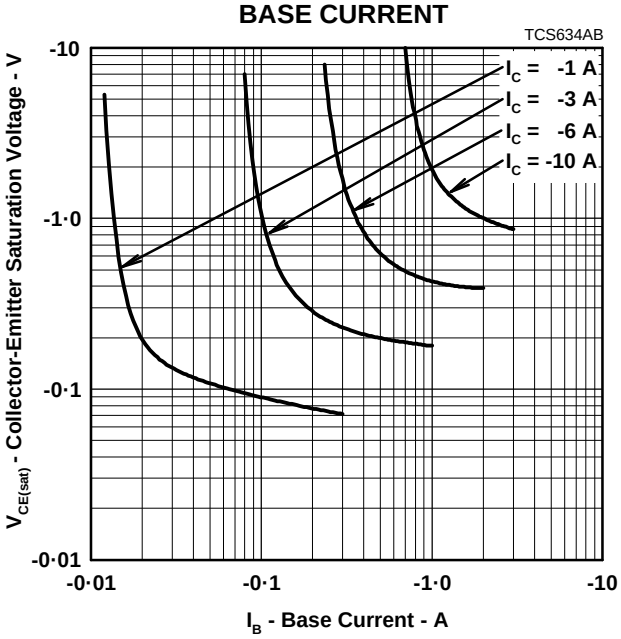


Figure 2.

BASE-EMITTER VOLTAGE vs COLLECTOR CURRENT

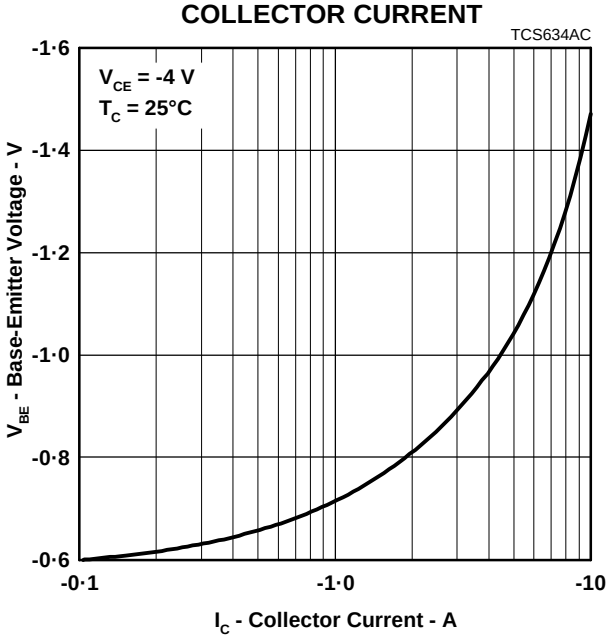


Figure 3.

MAXIMUM SAFE OPERATING REGIONS

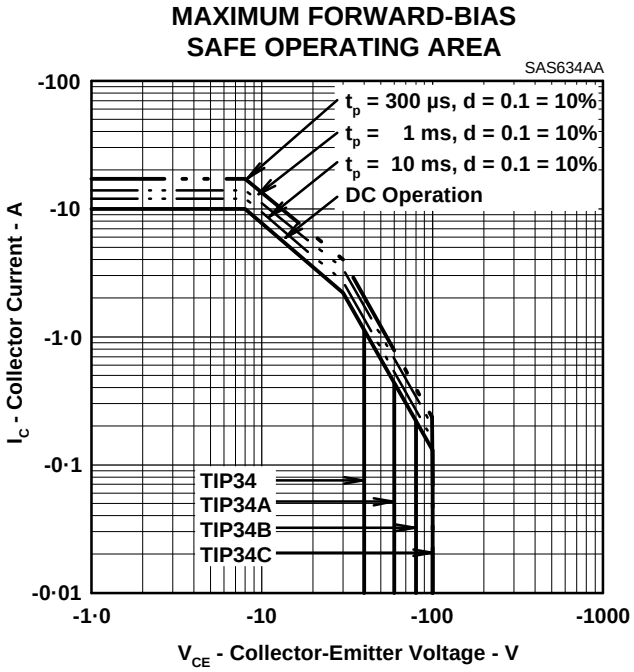


Figure 4.

THERMAL INFORMATION

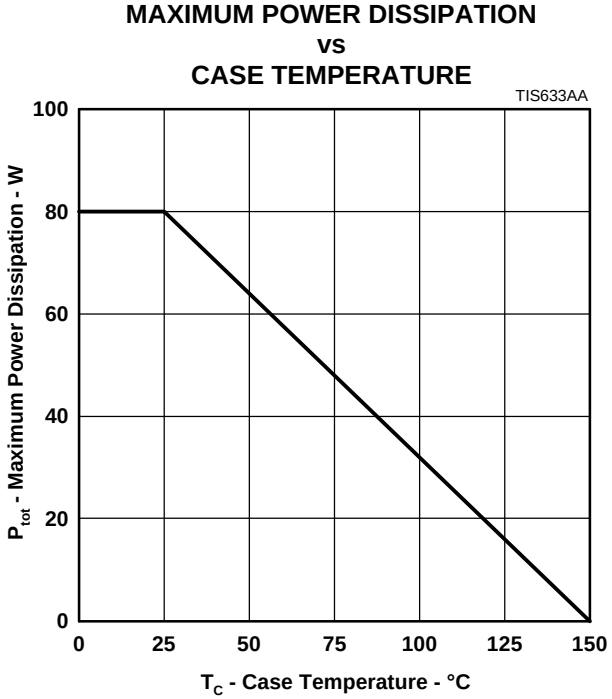


Figure 5.

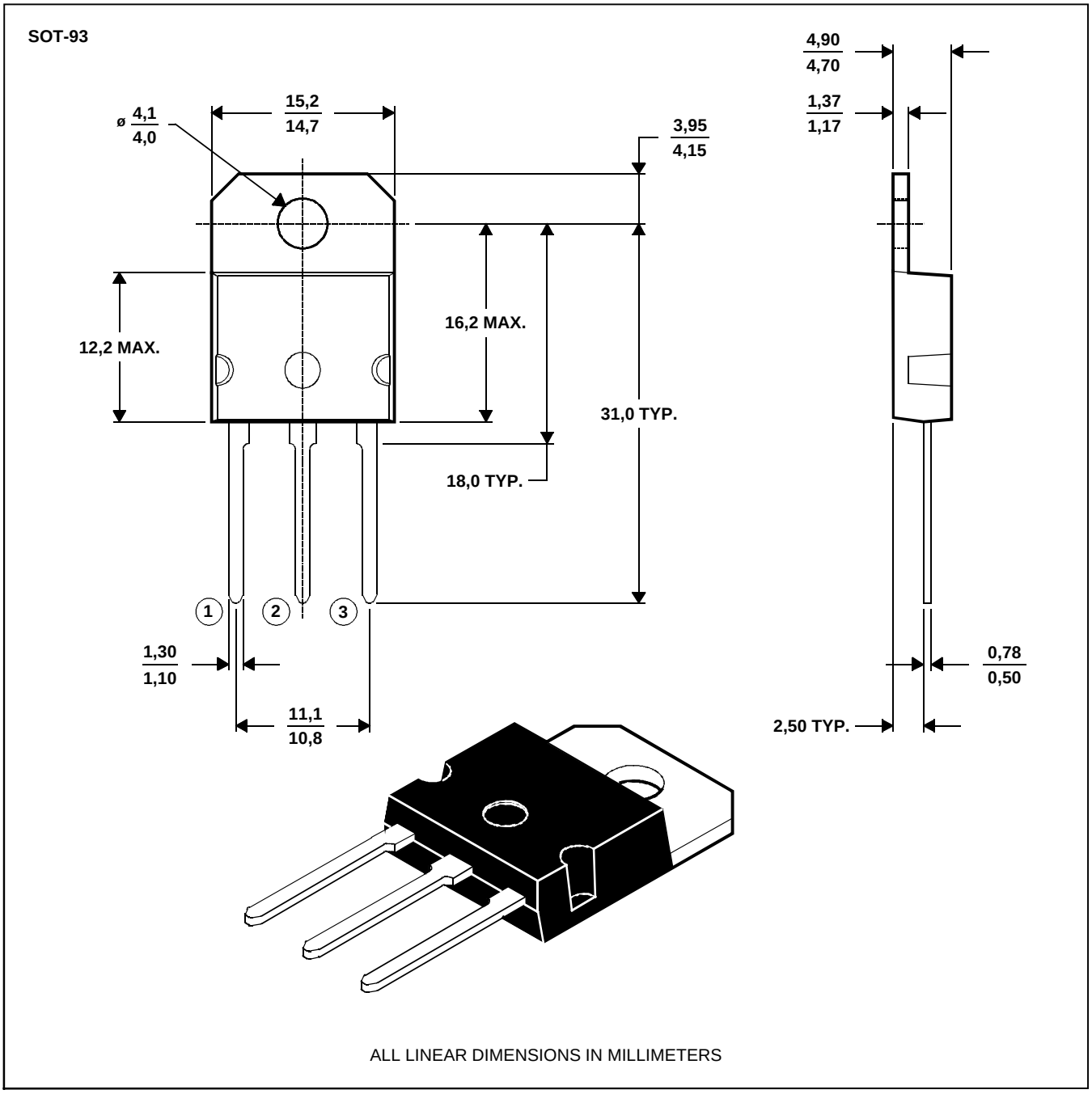
PRODUCT INFORMATION

JULY 1968 - REVISED MARCH 1997

MECHANICAL DATA

SOT-93
3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTE A: The centre pin is in electrical contact with the mounting tab.

MDXXAW

IMPORTANT NOTICE

Power Innovations Limited (PI) reserves the right to make changes to its products or to discontinue any semiconductor product or service without notice, and advises its customers to verify, before placing orders, that the information being relied on is current.

PI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with PI's standard warranty. Testing and other quality control techniques are utilized to the extent PI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except as mandated by government requirements.

PI accepts no liability for applications assistance, customer product design, software performance, or infringement of patents or services described herein. Nor is any license, either express or implied, granted under any patent right, copyright, design right, or other intellectual property right of PI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used.

PI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, INTENDED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT APPLICATIONS, DEVICES OR SYSTEMS.